Electronic Version v1.1 Stylesheet Version v1.1

SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT

CONVEYING PARTY DATA

Name	Execution Date
Xiangfeng Duan	07/16/2008
Jian Chen	07/16/2008
J. Wallace Parce	07/16/2008
Francisco A. Leon	07/16/2008

RECEIVING PARTY DATA

Name:	Nanosys, Inc.	
Street Address:	2625 Hanover Street	
City:	Palo Alto	
State/Country:	CALIFORNIA	
Postal Code: 94304		

PROPERTY NUMBERS Total: 1

Property Type	Number
Application Number:	12121591

CORRESPONDENCE DATA

Fax Number: (650)331-2191

Correspondence will be sent via US Mail when the fax attempt is unsuccessful.

Phone: 6503312194

Email: mchan@nanosysinc.com

Correspondent Name: Nanosys, Inc.

Address Line 1: 2625 Hanover Street

Address Line 4: Palo Alto, CALIFORNIA 94304

ATTORNEY DOCKET NUMBER: 01-009320

NAME OF SUBMITTER: Michelle Chan

Total Attachments: 2

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PATENT REEL: 021274 FRAME: 0097

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PATENT REEL: 021274 FRAME: 0098

ASSIGNMENT OF PATENT APPLICATION

IOINT

WHEREAS Xiangieng Duan of 715 Gayley Avenue Apt, #403, Los Angeles, CA 90024, Jian Chen of 777 W. Middlefield Road, Apt. 61, Mountain View, CA 94043, J. Wallace Parce of 754 Los Robles Avenue, Palo Alto, CA 94306 and Francisco A. Leon of 777 Addison Avenue, Palo Alto, CA 94301, hereinafter referred to as "Assignor(s)," is/are the inventor(s) of the invention described and set forth in the below identified application for a United States Letters Patent:

Gate Electrode for a Nonvolatile Memory Cell

Title of the Invention:

i ining Date.	MIN 15, 2008	
Serial No.:	12/121,591	and
77307, neremane	i referred to as "Assignce," is de	corporation located at 2625 Hanover Street, Palo Alto, CA sirous of acquiring an interest in the invention and tions which may be granted on the same;
invention and app designs), and in a the United States by the Paris Conv successors and as this assignment no granted thereon, of	objection and to all foreign countered to any Letters Patent and Regard and all countries of the world, are ention. The right, title and interestigns as fully and exclusively as put been made, for the full term of the public term of the countries.	hich is hereby acknowledged by Assignor(s), Assignor(s) Assignee all right, title and interest in and to the erparts (including patent, utility model, and industrial istrations which may hereafter be granted on the same in ad to claim the priority from the application as provided est is to be held and enjoyed by Assignee and Assignce's it would have been held and enjoyed by Assignor(s) had any Letters Patent and Registrations which may be mustion, in-whole or in-part, substitution, conversion,
invention and any including patent a lawfully may requ	improvements. (b) execute, veri- pplications and instruments of tra- est to obtain or maintain Letters	vithout charge to Assignee, but at Assignee's expense, (a). Patent applications and foreign counterparts on the fy. acknowledge and deliver all such further papers, ansfer and (c) perform such other acts as Assignee Patents and Registrations for the invention and title thereto in Assignee or Assignee's successors and
indicated.	IN TESTIMONY WHEREOF, A	assignor(s) has signed his or her name on the date
Date:7	1.6/08	
		Xiangfeng Duan
Date:		
		Jian Chen
Date:		
		J. Wallace Parce
Datc:		
		Francisco A. Leon

PATENT REEL: 021274 FRAME: 0099

ASSIGNMENT OF PATENT APPLICATION

JOINT

WHEREAS Xiangfeng Duan of 715 Gayley Avenue Apt. #403, Los Angeles, CA 90024, Jian Chen of 777 W. Middlefield Road, Apt. 61, Mountain View, CA 94043, J. Wallace Parce of 754 Los Robles Avenue, Palo Alto, CA 94306 and Francisco A. Leon of 777 Addison Avenue, Palo Alto, CA 94301, hereinafter referred to as "Assignor(s)," is/are the inventor(s) of the invention described and set forth in the below identified application for a United States Letters Patent:

Gate Electrode for a Nonvolatile Memory Cell

Title of the Invention:

RECORDED: 07/22/2008

Filing Da	ate:	May 15, 2008			
Serial No	o.:	12/121,591	; and		
WHEREAS, NANOSYS, INC., a DELAWARE corporation located at 2625 Hanover Street, Palo Alto, CA 94304, hereinafter referred to as "Assignee," is desirous of acquiring an interest in the invention and application and in any Letters Patent and Registrations which may be granted on the same;					
has assig invention designs), the Unite by the Pa successo this assig granted t reissue, p	gned, and by an and applica, and in and the distance and aris Conventions and assign and assignment not be thereon, or of prolongation ar(s) further against the distance are also and application and application are also are also and application are also and application are also and are also are also and are also and are also are also are also and are also and are also and are also ar	these presents does as tion and to all foreign o any Letters Patent a all countries of the won. The right, title and as as fully and exclusiveen made, for the full any division, renewal or extension thereof. The right was a subject to the full any division, renewal or extension thereof.	pt of which is hereby acknowledged by Assignor(s), Assignor(s) sign to Assignee all right, title and interest in and to the a counterparts (including patent, utility model, and industrial and Registrations which may hereafter be granted on the same in orld, and to claim the priority from the application as provided and interest is to be held and enjoyed by Assignee and Assignee's evely as it would have been held and enjoyed by Assignor(s) had term of any Letters Patent and Registrations which may be all, continuation, in-whole or in-part, substitution, conversion,		
cooperat invention including lawfully	e with Assign and any img patent applemay request	nee in the prosecution provements, (b) execu ications and instrument to obtain or maintain	of U.S. Patent applications and foreign counterparts on the ate, verify, acknowledge and deliver all such further papers, into of transfer and (c) perform such other acts as Assignee Letters Patents and Registrations for the invention and I to vest title thereto in Assignee or Assignee's successors and		
indicated		TESTIMONY WHEF	REOF, Assignor(s) has signed his or her name on the date		
Date:					
Date:	2/1	6/08	Xiangfeng Duan Jian Chen		
Date:	211	6/08	J. Wallace Parce		
Date:	7/1	6/2008	Itam A. h		

PATENT REEL: 021274 FRAME: 0100

Francisco A. Leon